

SN74LS253

Dual 4-Input Multiplexer with 3-State Outputs

The LSTTL/MSI SN74LS253 is a Dual 4-Input Multiplexer with 3-state outputs. It can select two bits of data from four sources using common select inputs. The outputs may be individually switched to a high impedance state with a HIGH on the respective Output Enable (\bar{E}_0) inputs, allowing the outputs to interface directly with bus oriented systems. It is fabricated with the Schottky barrier diode process for high speed and is completely compatible with all ON Semiconductor TTL families.

- Schottky Process for High Speed
- Multifunction Capability
- Non-Inverting 3-State Outputs
- Input Clamp Diodes Limit High Speed Termination Effects

GUARANTEED OPERATING RANGES

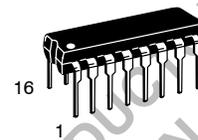
Symbol	Parameter	Min	Typ	Max	Unit
V_{CC}	Supply Voltage	4.75	5.0	5.25	V
T_A	Operating Ambient Temperature Range	0	25	70	°C
I_{OH}	Output Current – High			-2.6	mA
I_{OL}	Output Current – Low			24	mA



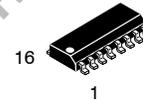
ON Semiconductor™

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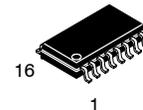
LOW
POWER
SCHOTTKY



PLASTIC
N SUFFIX
CASE 648



SOIC
D SUFFIX
CASE 751B



SOEIAJ
M SUFFIX
CASE 966

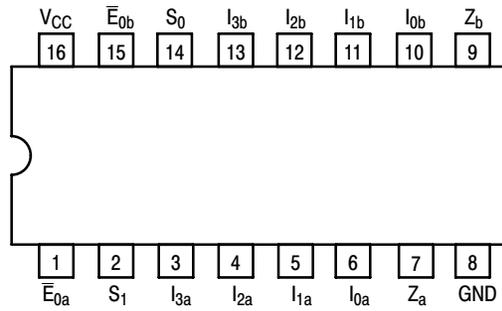
ORDERING INFORMATION

Device	Package	Shipping
SN74LS253N	16 Pin DIP	2000 Units/Box
SN74LS253D	SOIC-16	38 Units/Rail
SN74LS253DR2	SOIC-16	2500/Tape & Reel
SN74LS253M	SOEIAJ-16	See Note 1
SN74LS253MEL	SOEIAJ-16	See Note 1

1. For ordering information on the EIAJ version of the SOIC package, please contact your local ON Semiconductor representative.

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CONNECTION DIAGRAM DIP (TOP VIEW)



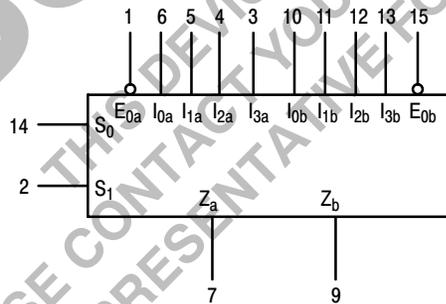
NOTE:
The Flatpak version has the same pinouts (Connection Diagram) as the Dual In-Line Package.

PIN NAMES		LOADING (Note a)	
		HIGH	LOW
S_0, S_1	Common Select Inputs	0.5 U.L.	0.25 U.L.
Multiplexer A			
\bar{E}_{0a}	Output Enable (Active LOW) Input	0.5 U.L.	0.25 U.L.
$I_{0a} - I_{3a}$	Multiplexer Inputs	0.5 U.L.	0.25 U.L.
Z_a	Multiplexer Output	65 U.L.	15 U.L.
Multiplexer B			
\bar{E}_{0b}	Output Enable (Active LOW) Input	0.5 U.L.	0.25 U.L.
$I_{0b} - I_{3b}$	Multiplexer Inputs	0.5 U.L.	0.25 U.L.
Z_b	Multiplexer Output	65 U.L.	15 U.L.

NOTES:

a) 1 TTL Unit Load (U.L.) = 40 μ A HIGH/1.6 mA LOW.

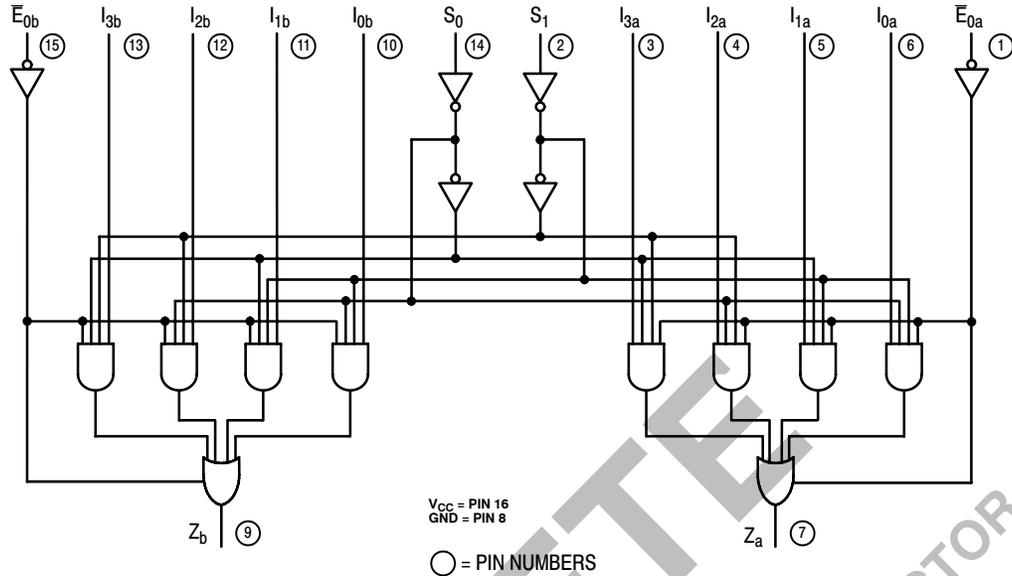
LOGIC SYMBOL



V_{CC} = PIN 16
GND = PIN 8

SN74LS253

LOGIC DIAGRAM



FUNCTIONAL DESCRIPTION

The LS253 contains two identical 4-Input Multiplexers with 3-state outputs. They select two bits from four sources selected by common select inputs (S_0 , S_1). The 4-input multiplexers have individual Output Enable (\bar{E}_{0a} , \bar{E}_{0b}) inputs which when HIGH, forces the outputs to a high impedance (high Z) state.

The LS253 is the logic implementation of a 2-pole, 4-position switch, where the position of the switch is determined by the logic levels supplied to the two select inputs. The logic equations for the outputs are shown below:

$$Z_a = \bar{E}_{0a} \cdot (I_{0a} \cdot \bar{S}_1 \cdot \bar{S}_0 + I_{1a} \cdot \bar{S}_1 \cdot S_0 + I_{2a} \cdot S_1 \cdot \bar{S}_0 + I_{3a} \cdot S_1 \cdot S_0)$$

$$Z_b = \bar{E}_{0b} \cdot (I_{0b} \cdot \bar{S}_1 \cdot \bar{S}_0 + I_{1b} \cdot \bar{S}_1 \cdot S_0 + I_{2b} \cdot S_1 \cdot \bar{S}_0 + I_{3b} \cdot S_1 \cdot S_0)$$

If the outputs of 3-state devices are tied together, all but one device must be in the high impedance state to avoid high currents that would exceed the maximum ratings. Designers should ensure that Output Enable signals to 3-state devices whose outputs are tied together are designed so that there is no overlap.

TRUTH TABLE

SELECT INPUTS		DATA INPUTS				OUTPUT ENABLE	OUTPUT
S_0	S_1	I_0	I_1	I_2	I_3	E_0	Z
X	X	X	X	X	X	H	(Z)
L	L	L	X	X	X	L	L
L	L	H	X	X	X	L	H
H	L	X	L	X	X	L	L
H	L	X	H	X	X	L	H
L	H	X	X	L	X	L	L
L	H	X	X	H	X	L	H
H	H	X	X	X	L	L	L
H	H	X	X	X	H	L	H

H = HIGH Level

L = LOW Level

X = Irrelevant

(Z) = High Impedance (off)

Address inputs S_0 and S_1 are common to both sections.

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DC CHARACTERISTICS OVER OPERATING TEMPERATURE RANGE (unless otherwise specified)

Symbol	Parameter	Limits			Unit	Test Conditions	
		Min	Typ	Max			
V _{IH}	Input HIGH Voltage	2.0			V	Guaranteed Input HIGH Voltage for All Inputs	
V _{IL}	Input LOW Voltage			0.8	V	Guaranteed Input LOW Voltage for All Inputs	
V _{IK}	Input Clamp Diode Voltage		-0.65	-1.5	V	V _{CC} = MIN, I _{IN} = -18 mA	
V _{OH}	Output HIGH Voltage	2.4	3.1		V	V _{CC} = MIN, I _{OH} = MAX, V _{IN} = V _{IH} or V _{IL} per Truth Table	
V _{OL}	Output LOW Voltage		0.25	0.4	V	I _{OL} = 12 mA I _{OL} = 24 mA	V _{CC} = V _{CC} MIN, V _{IN} = V _{IL} or V _{IH} per Truth Table
			0.35	0.5	V		
I _{OZH}	Output Off Current HIGH			20	μA	V _{CC} = MAX, V _{OUT} = 2.7 V	
I _{OZL}	Output Off Current LOW			-20	μA	V _{CC} = MAX, V _{OUT} = 0.4 V	
I _{IH}	Input HIGH Current			20	μA	V _{CC} = MAX, V _{IN} = 2.7 V	
				0.1	mA	V _{CC} = MAX, V _{IN} = 7.0 V	
I _{IL}	Input LOW Current			-0.4	mA	V _{CC} = MAX, V _{IN} = 0.4 V	
I _{OS}	Short Circuit Current (Note 2)	-30		-130	mA	V _{CC} = MAX	
I _{CC}	Power Supply Current			12	mA	V _{CC} = MAX, V _E = 0 V	
				14	mA	V _{CC} = MAX, V _E = 4.5 V	

2. Not more than one output should be shorted at a time, nor for more than 1 second.

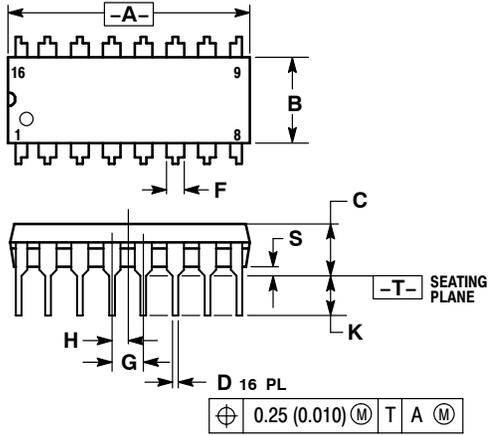
AC CHARACTERISTICS (T_A = 25°C, V_{CC} = 5.0 V) See SN74LS251 for Waveforms

Symbol	Parameter	Limits			Unit	Test Conditions
		Min	Typ	Max		
t _{PLH} t _{PHL}	Propagation Delay, Data to Output		17 13	25 20	ns	Figure 1
t _{PLH} t _{PHL}	Propagation Delay, Select to Output		30 21	45 32	ns	Figure 1
t _{PZH} t _{PZL}	Output Enable Time		15 15	28 23	ns	Figures 4, 5
t _{PHZ} t _{PLZ}	Output Disable Time		27 18	41 27	ns	Figures 3, 5

SN74LS253

PACKAGE DIMENSIONS

N SUFFIX
PLASTIC PACKAGE
CASE 648-08
ISSUE R



NOTES:

1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
2. CONTROLLING DIMENSION: INCH.
3. DIMENSION L TO CENTER OF LEADS WHEN FORMED PARALLEL.
4. DIMENSION B DOES NOT INCLUDE MOLD FLASH.
5. ROUNDED CORNERS OPTIONAL.

DIM	INCHES		MILLIMETERS	
	MIN	MAX	MIN	MAX
A	0.740	0.770	18.80	19.55
B	0.250	0.270	6.35	6.85
C	0.145	0.175	3.69	4.44
D	0.015	0.021	0.39	0.53
F	0.040	0.70	1.02	1.77
G	0.100 BSC		2.54 BSC	
H	0.050 BSC		1.27 BSC	
J	0.008	0.015	0.21	0.38
K	0.110	0.130	2.80	3.30
L	0.295	0.305	7.50	7.74
M	0° 10°		0° 10°	
S	0.020	0.040	0.51	1.01

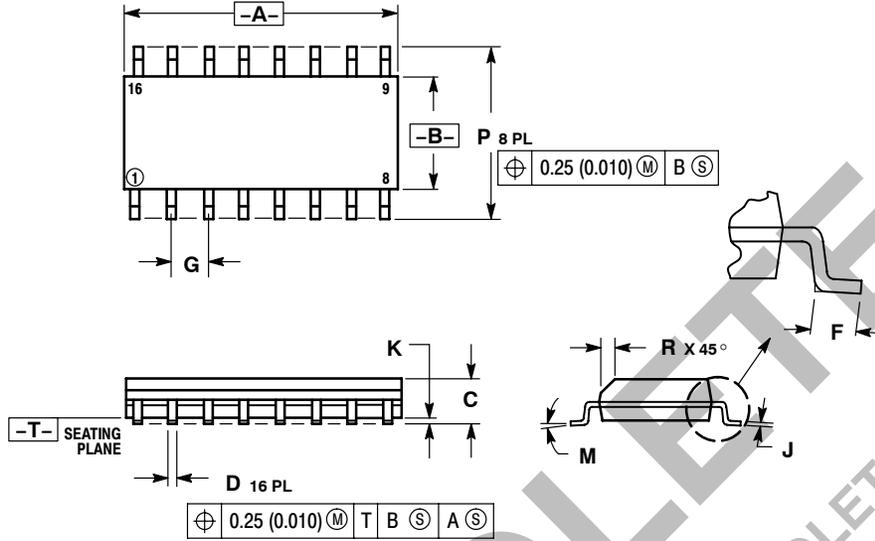
OBSOLETE

THIS DEVICE IS OBSOLETE
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 REPRESENTATIVE FOR INFORMATION

SN74LS253

PACKAGE DIMENSIONS

D SUFFIX PLASTIC SOIC PACKAGE CASE 751B-05 ISSUE J



NOTES:

1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
2. CONTROLLING DIMENSION: MILLIMETER.
3. DIMENSIONS A AND B DO NOT INCLUDE MOLD PROTRUSION.
4. MAXIMUM MOLD PROTRUSION 0.15 (0.006) PER SIDE.
5. DIMENSION D DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE DAMBAR PROTRUSION SHALL BE 0.127 (0.005) TOTAL IN EXCESS OF THE D DIMENSION AT MAXIMUM MATERIAL CONDITION.

DIM	MILLIMETERS		INCHES	
	MIN	MAX	MIN	MAX
A	9.80	10.00	0.386	0.393
B	3.80	4.00	0.150	0.157
C	1.35	1.75	0.054	0.068
D	0.35	0.49	0.014	0.019
F	0.40	1.25	0.016	0.049
G	1.27 BSC		0.050 BSC	
J	0.19	0.25	0.008	0.009
K	0.10	0.25	0.004	0.009
M	0°		7°	
P	5.80	6.20	0.229	0.244
R	0.25	0.50	0.010	0.019

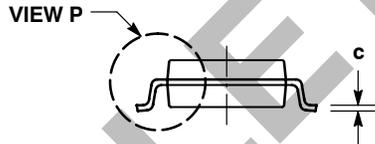
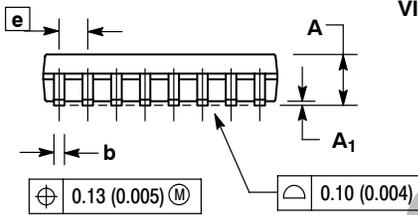
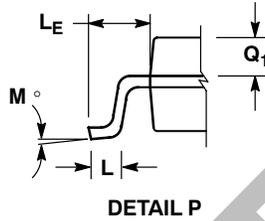
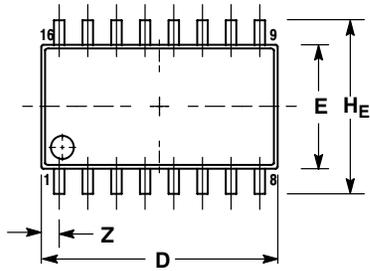
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SN74LS253

PACKAGE DIMENSIONS

M SUFFIX
SOEIAJ PACKAGE
CASE 966-01
ISSUE O



NOTES:

1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
2. CONTROLLING DIMENSION: MILLIMETER.
3. DIMENSIONS D AND E DO NOT INCLUDE MOLD FLASH OR PROTRUSIONS AND ARE MEASURED AT THE PARTING LINE. MOLD FLASH OR PROTRUSIONS SHALL NOT EXCEED 0.15 (0.006) PER SIDE.
4. TERMINAL NUMBERS ARE SHOWN FOR REFERENCE ONLY.
5. THE LEAD WIDTH DIMENSION (b) DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE DAMBAR PROTRUSION SHALL BE 0.08 (0.003) TOTAL IN EXCESS OF THE LEAD WIDTH DIMENSION AT MAXIMUM MATERIAL CONDITION. DAMBAR CANNOT BE LOCATED ON THE LOWER RADIUS OR THE FOOT. MINIMUM SPACE BETWEEN PROTRUSIONS AND ADJACENT LEAD TO BE 0.46 (0.018).

DIM	MILLIMETERS		INCHES	
	MIN	MAX	MIN	MAX
A	---	2.05	---	0.081
A ₁	0.05	0.20	0.002	0.008
b	0.35	0.50	0.014	0.020
c	0.18	0.27	0.007	0.011
D	9.90	10.50	0.390	0.413
E	5.10	5.45	0.201	0.215
e	1.27 BSC		0.050 BSC	
HE	7.40	8.20	0.291	0.323
L	0.50	0.85	0.020	0.033
LE	1.10	1.50	0.043	0.059
M	0° 10°		0° 10°	
Q ₁	0.70	0.90	0.028	0.035
Z	---	0.78	---	0.031

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